

Ordering number : ENN7148

P-Channel Silicon MOSFET

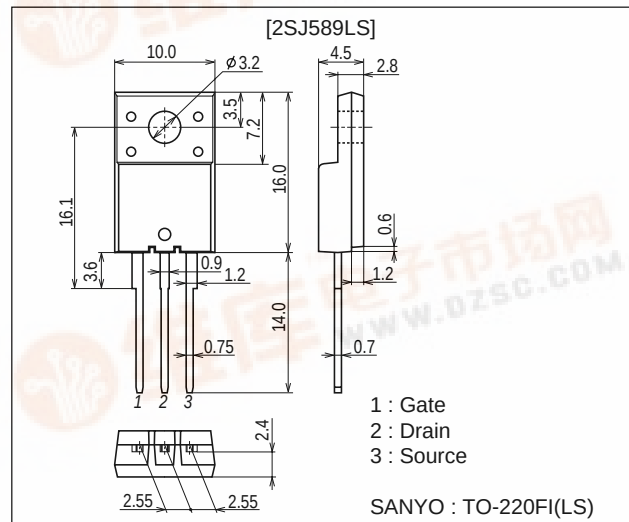
SANYO**2SJ589LS****DC / DC Converter Applications****Features**

- Low ON-resistance.
- 4V drive.

Package Dimensions

unit : mm

2078C

**Specifications****Absolute Maximum Ratings** at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DS}		-60	V
Gate-to-Source Voltage	V_{GS}		± 20	V
Drain Current (DC)	I_D		-15	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	-60	A
Allowable Power Dissipation	P_D	$T_c=25^\circ\text{C}$	2.0	W
			25	W
Channel Temperature	T_{ch}		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DS}$	$I_D=-1\text{mA}$, $V_{GS}=0$	-60			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-60\text{V}$, $V_{GS}=0$			-10	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 16\text{V}$, $V_{DS}=0$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=-10\text{V}$, $I_D=-1\text{mA}$	-1.0		-2.4	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=-10\text{V}$, $I_D=-8\text{A}$	10	14		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D=-8\text{A}$, $V_{GS}=-10\text{V}$		58	80	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D=-8\text{A}$, $V_{GS}=-4\text{V}$		80	115	$\text{m}\Omega$

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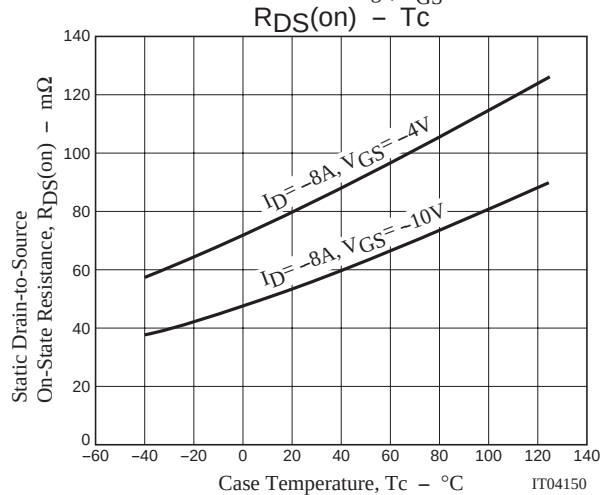
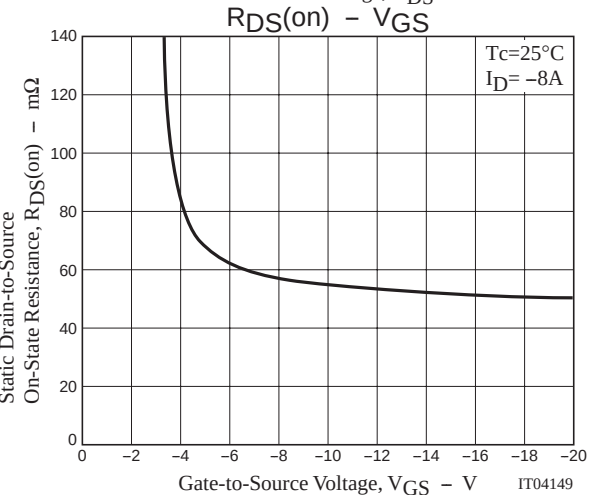
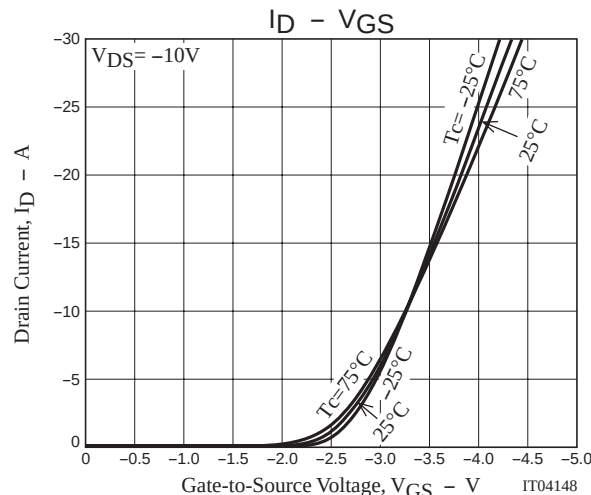
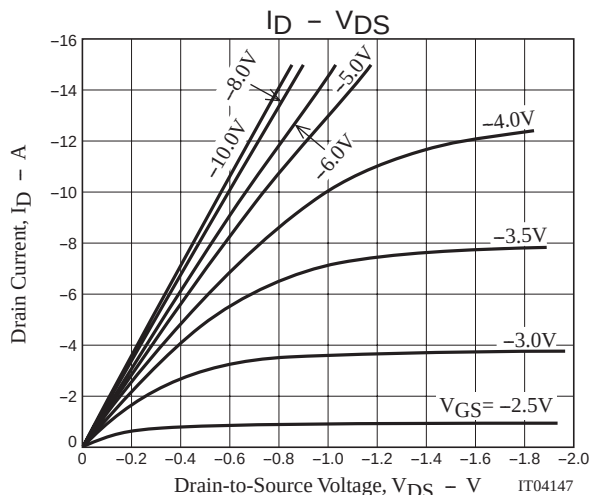
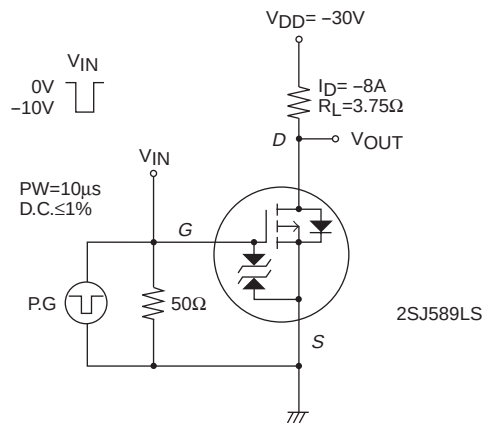
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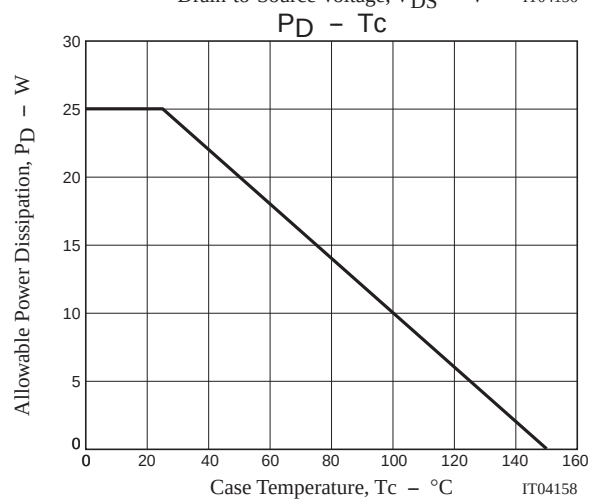
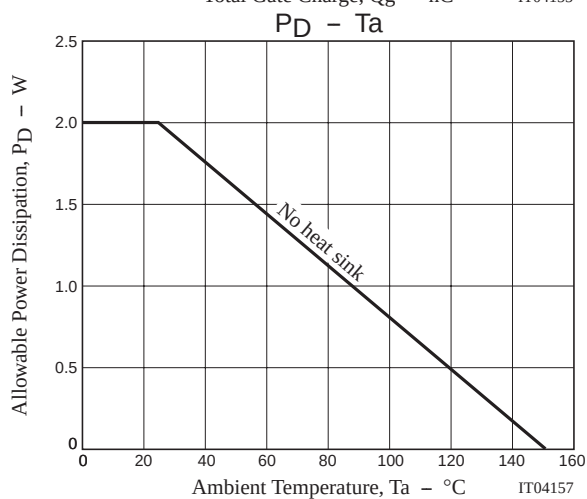
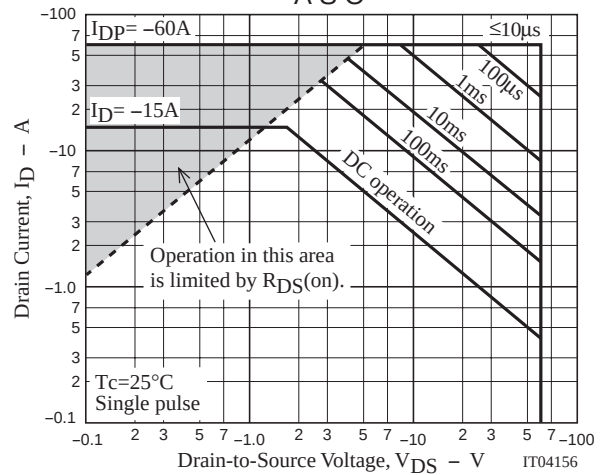
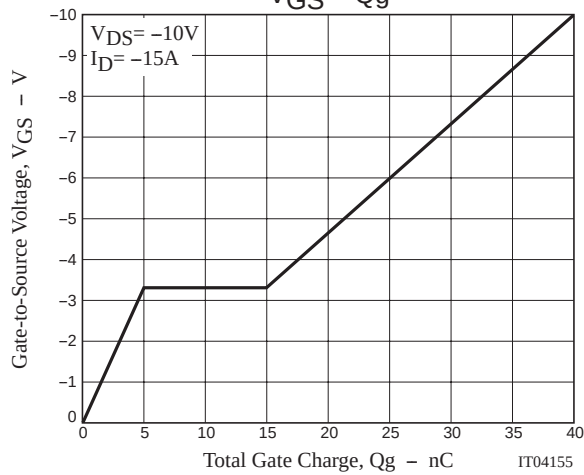
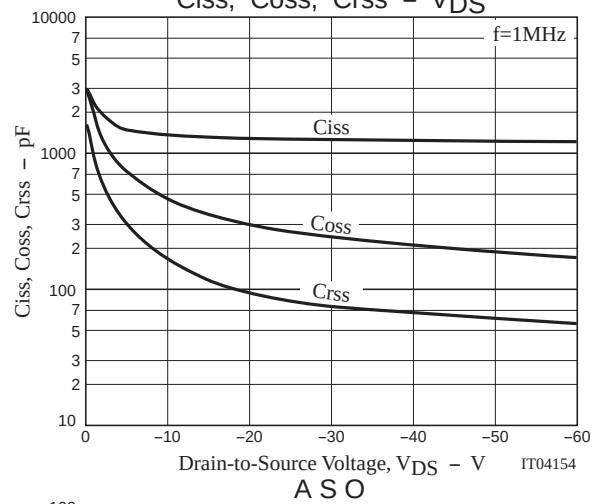
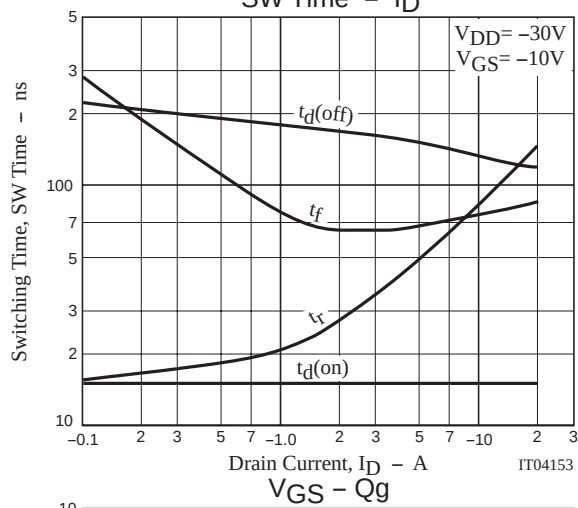
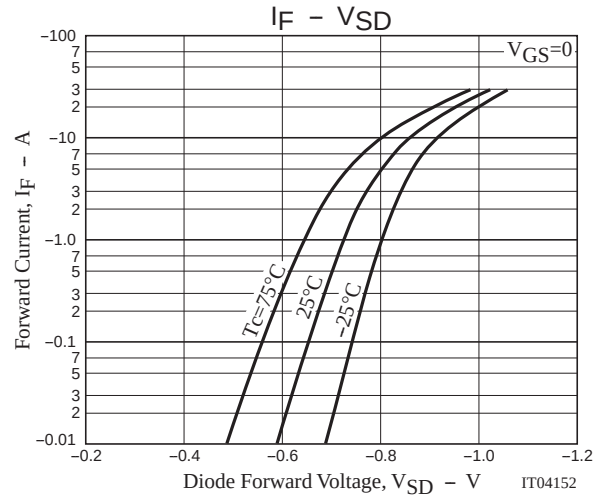
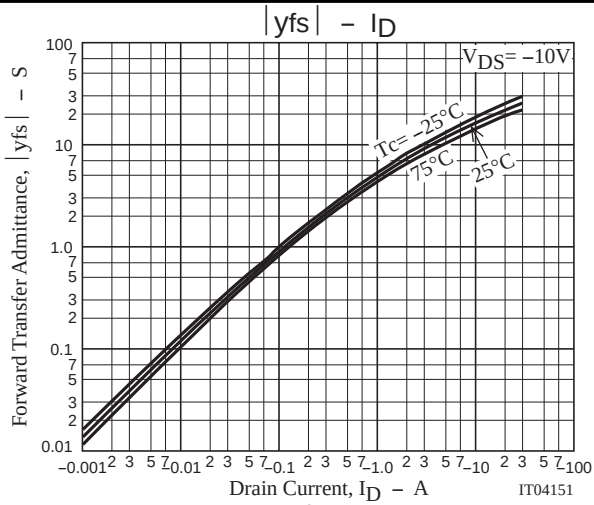
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	VDS=-20V, f=1MHz		1300		pF
Output Capacitance	Coss	VDS=-20V, f=1MHz		300		pF
Reverse Transfer Capacitance	Crss	VDS=-20V, f=1MHz		90		pF
Turn-ON Delay Time	td(on)	See specified Test Circuit.		15		ns
Rise Time	tr	See specified Test Circuit.		70		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		140		ns
Fall Time	tf	See specified Test Circuit.		72		ns
Total Gate Charge	Qg	VDS=-10V, VGS=-10V, ID=-15A		40		nC
Gate-to-Source Charge	Qgs	VDS=-10V, VGS=-10V, ID=-15A		5		nC
Gate-to-Drain "Miller" Charge	Qgd	VDS=-10V, VGS=-10V, ID=-15A		10		nC
Diode Forward Voltage	VSD	IS=-15A, VGS=0		-0.91	-1.2	V

Switching Time Test Circuit



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